



### Main Features:

- Frequency Range: 5 to 6 GHz.
- Typical values: P1dB 26 dBm, Gain 25 dB
- RF connectors (I/O): SMA
- Solder filtered pins for DC connection
- Several mounting options
- Gold plated compact aluminum housing
- Hi-reliability and dedicated screening/ environmental tests available under request

### ERZ-LNA-0500-0600-25

The ERZ-HPA-0500-0600-25 is a High Power Amplifier providing an output power of 26 dBm and a gain of 25 dB. The compact size and modularity makes it ideal for a wide range of applications.

### Typical applications:

- Industrial / Laboratory
- Satcom / Telecom
- Space / Aerospace / Military

### Performance

Parameter	Value			Units
	Min	Typ	Max	
Frequency	5	-	6	GHz
Output Power (P1dB)	24	26	28	dBm
Small Signal Gain	24	25	26	dB
Gain Flatness	-	±0.5	-	dB
Noise Figure	-	-	-	dB
VSWR input	-	-	2.0:1	-
VSWR output	-	-	2.0:1	-
DC Voltage	9	12	15	V
Power Consumption (@P1dB)	-	4.5	-	W
RF Connectors	SMA Female IN/OUT			-

Specifications at a case temperature of 25°C

### Output Power at 1 dB Compression

Figure 1 shows output power at 1dB compression measurement as a function of frequency at room temperature (25°C).

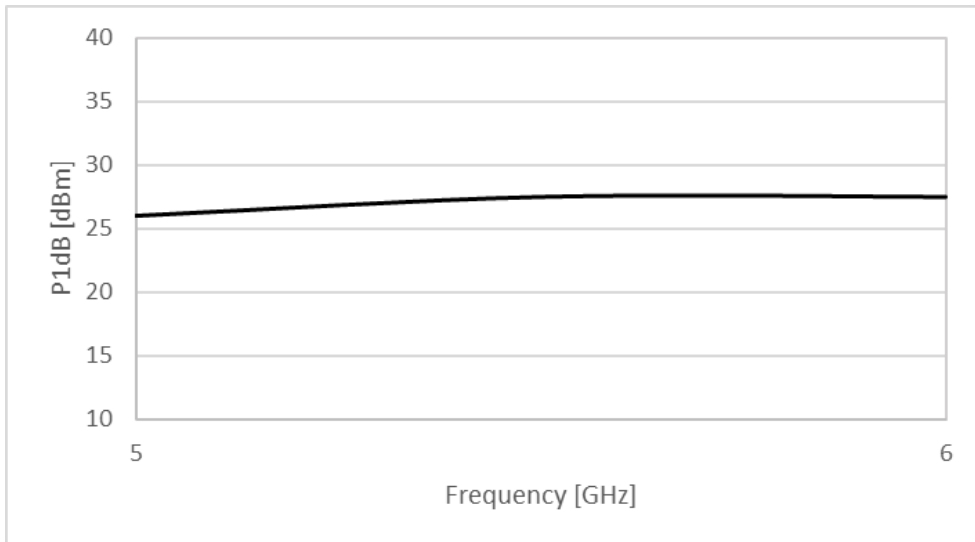


Figure 1: ERZ-HPA-0500-0600-25 P1dB

### Small Signal Gain

Figure 2 shows the small signal gain measurement as a function of frequency at room temperature (25°C).

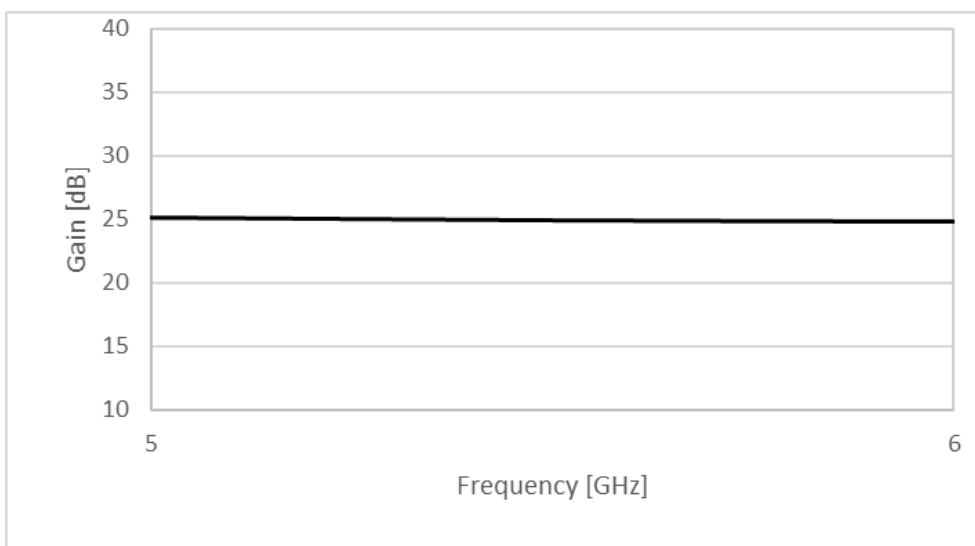


Figure 2: ERZ-HPA-0500-0600-25 Small Signal Gain

### Measurements Conditions

All measurements provided in this report were performed at the following conditions:

Condition	Value
Temperature	25°C ± 1°C
Humidity	50% ± 10%
DUT Warm up time	30 min
Test equipment warm up time	60 min

### Absolute Maximum Ratings

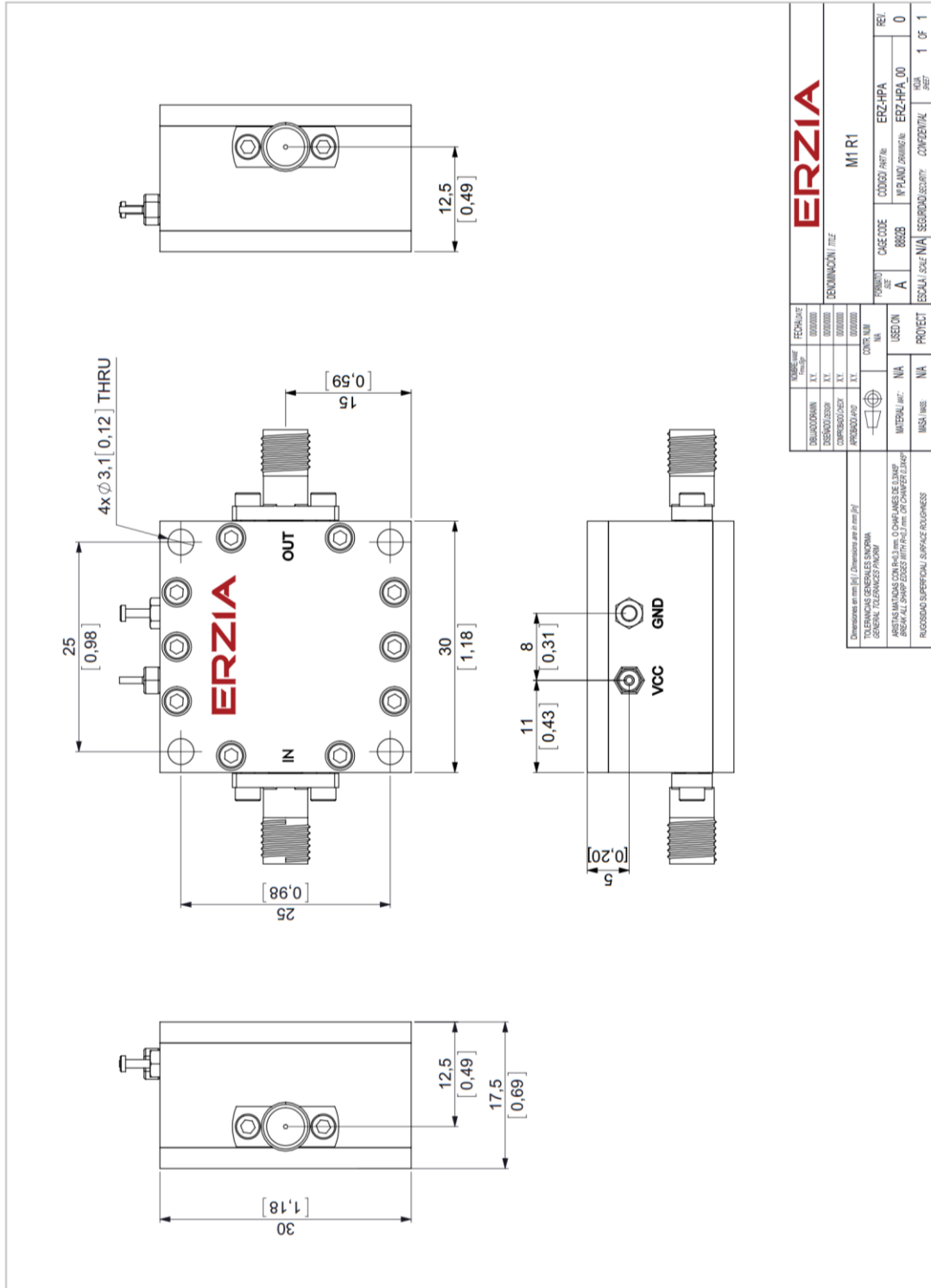
Condition	Value
DC Voltage	+15 VDC
Maximum Input Power (CW)	8 dBm
Operation temperatura (at case)	-40 to 85°C
Storage temperature	-55 to 125°C

- Stress above these ratings may cause permanent damage to the device.
- It is final user responsibility to maintain the amplifier within the specified ranges.

### Environmental Specifications (By Design)

Operating Temperature:	-45 to +85 °C	(MIL-STD-810F, method 520.2)
Storage Temperature:	-55 to 125 °C	(MIL-STD-810F, method 520.2)
Vibration:	8g rms	(MIL-STD-810F, method 514.5)
Shock:	20g,11ms,saw-tooth	(MIL-STD-810F, method 516.5)
Acceleration:	15g	(MIL-STD-810F, method 513.5)

## Mechanics and Housing



### Documentation and Test Reports

All modules are at least delivered with: Electrical Test Report, Certificate of Conformance, Certificate of Acceptance and Origin. Optionally, units can be environmentally tested (temperature, vibration...).

### Option (HS): Heat Sink

A heat sink (HS) can be provided to allow the operation of Power Amplifiers. Please note that most power amplifiers need heat sink or appropriate heat dissipation strategy.

### Space / Military Usage

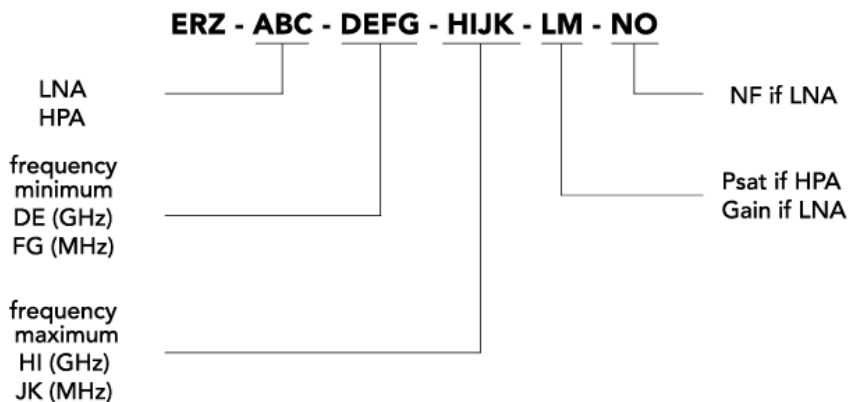
Most of ERZIA's products are based on rad-hard technologies and can be manufactured and integrated according to MIL / ECSS or specific hi-rel standard-screening for space, aeronautics, military or specific hi-reliability usage.

### Customization and Extended Performances

ERZIA can fully design or adapt one of the existing RF amplifiers designs according to your specifications. Please contact us for additional information.

### Model Number Codification

#### MODEL NUMBER



# ERZIA

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